

MOSFET – Power, N-Channel, Dual EFCP

24 V, 5 A, 46.2 m Ω

EFC4626R

Features

- 2.5 V Drive
- Protection Diode In
- Common-Drain Type
- 2 kV ESD HBM
- This Device is Pb–Free, Halogen Free/BFR Free and is RoHS Compliant

Applications

• Lithium-ion Battery Charging and Discharging Switch

Specifications

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C)

Parameter	Symbol	Conditions	Value	Unit
Source to Source Voltage	V _{SSS}		24	V
Gate to Source Voltage	V _{GSS}		±10	V
Source Current (DC)	I _S		5	Α
Source Current (Pulse)	I _{SP}	PW ≤ 10 μs, duty cycle ≤1%	60	Α
Total Dissipation	P _T	When mounted on ceramic substrate (5000 mm ² x 0.8 mm)	1.4	W
Junction Temperature	T_{J}		150	°C
Storage Temperature	T _{stg}		– 55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Value	Unit
Junction to Ambient When mounted on ceramic substrate (5000 mm ² x 0.8 mm)	$R_{ hetaJA}$	84	V



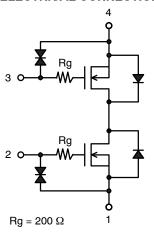
MARKING DIAGRAM



B = Specific Device Code Y = Year of Production

M = Assembly Operation MonthZZ = Assembly Lot Number

ELECTRICAL CONNECTION



ORDERING INFORMATION

Device	Package	Shipping [†]
EFC4626R-TR	CSP4 (Pb–Free and Halogen Free)	8000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS $(T_A = 25^{\circ}C)$

Parameter	Symbol	Condition	s	Min	Тур	Max	Unit
Source to Source Breakdown Voltage	V _{(BR)SSS}	I _S = 1 mA, V _{GS} = 0 V	Test Circuit 1	24	_	-	V
Zero-Gate Voltage Source Current	I _{SSS}	V _{SS} = 20 V, V _{GS} = 0 V	Test Circuit 1	-	_	1	μΑ
Gate to Source Leakage Current	I _{GSS}	$V_{GS} = \pm 8 \text{ V}, V_{SS} = 0 \text{ V}$	Test Circuit 2	_	_	±1	μΑ
Gate Threshold Voltage	V _{GS} (th)	V _{SS} = 10 V, I _S = 1 mA	Test Circuit 3	0.5	_	1.3	V
Forward Transconductance	9FS	V _{SS} = 10 V, I _S = 2 A	Test Circuit 4	-	7	-	S
Static Source to Source On–State Resistance	R _{SS} (on)1	I _S = 2 A, V _{GS} = 4.5 V	Test Circuit 5	29.2	37.5	46.2	mΩ
	R _{SS} (on)2	I _S = 2 A, V _{GS} = 4.0 V	Test Circuit 5	30.8	39.5	48.6	mΩ
	R _{SS} (on)3	I _S = 2 A, V _{GS} = 3.8 V	Test Circuit 5	32.0	41.0	50.5	mΩ
	R _{SS} (on)4	I _S = 2 A, V _{GS} = 3.1 V	Test Circuit 5	35.5	45.5	58.3	mΩ
	R _{SS} (on)5	I _S = 2 A, V _{GS} = 2.5 V	Test Circuit 5	42.6	54.0	72.4	mΩ
Turn-On Delay Time	t _d (on)	$V_{SS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V},$	Test Circuit 6	-	20	-	ns
Rise Time	t _r	I _S = 2 A		-	350	-	ns
Turn-Off Delay Time	t _d (off)			-	22000	-	ns
Fall Time	t _f			-	38400	-	ns
Total Gate Charge	Qg	$V_{SS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{S} = 5 \text{ A}$	Test Circuit 7	-	7.5	-	nC
Forward Source to Source Voltage	V _{F(S-S)}	I _S = 2 A, V _{GS} = 0 V	Test Circuit 8	-	0.81	1.2	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Test Circuits are Example of Measuring FET1 Side.

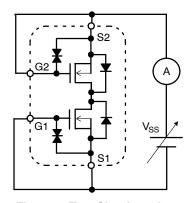
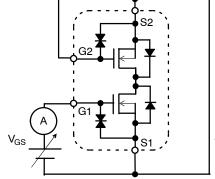


Figure 1. Test Circuit 1 - I_{SSS}



When FET1 is measured, Gate and Source of FET2 are short-circuited.

Figure 2. Test Circuit 2 - I_{GSS}

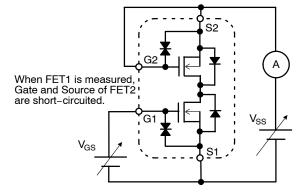


Figure 3. Test Circuit 3 - V_{GS}(th)

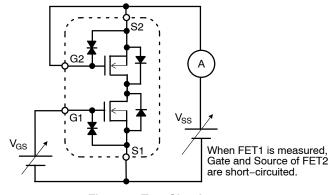
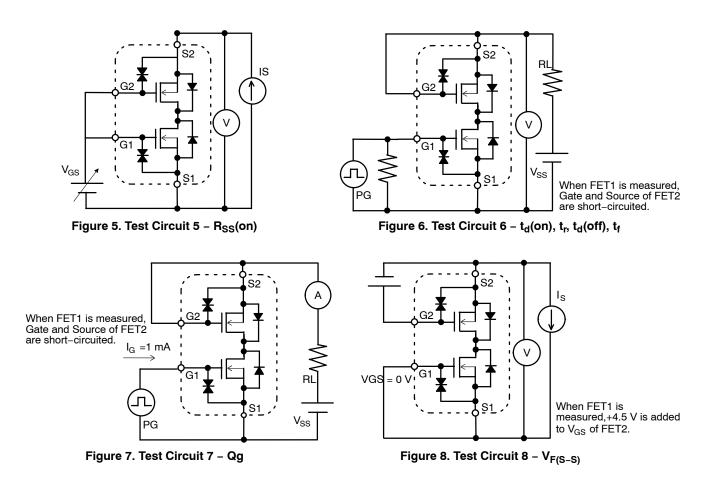


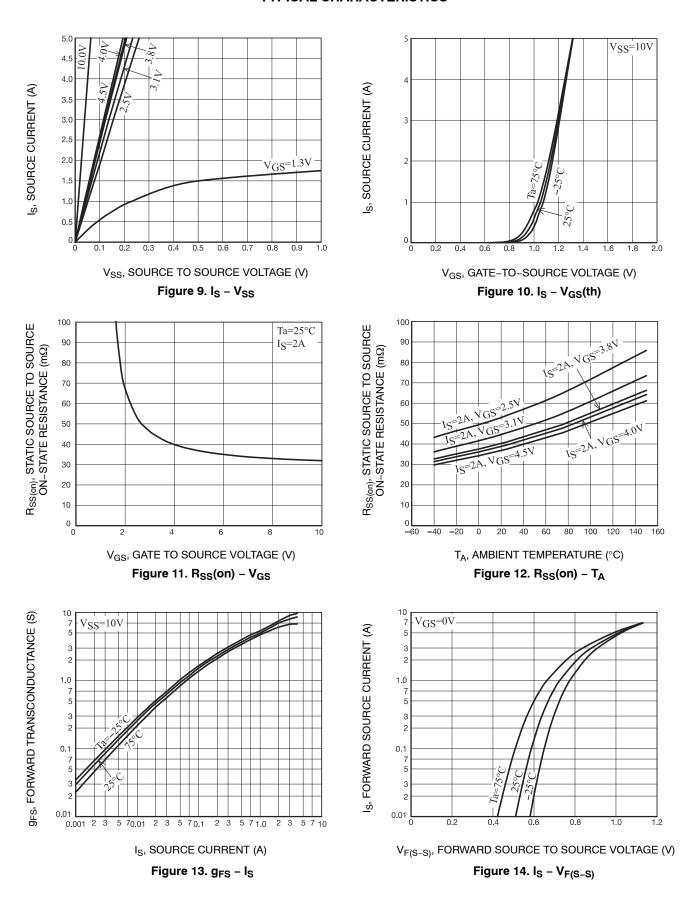
Figure 4. Test Circuit 4 - g_{FS}

TEST CIRCUITS (continued)



NOTE: When FET2 is measured, the position of FET1 and FET2 is switched.

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS (continued)

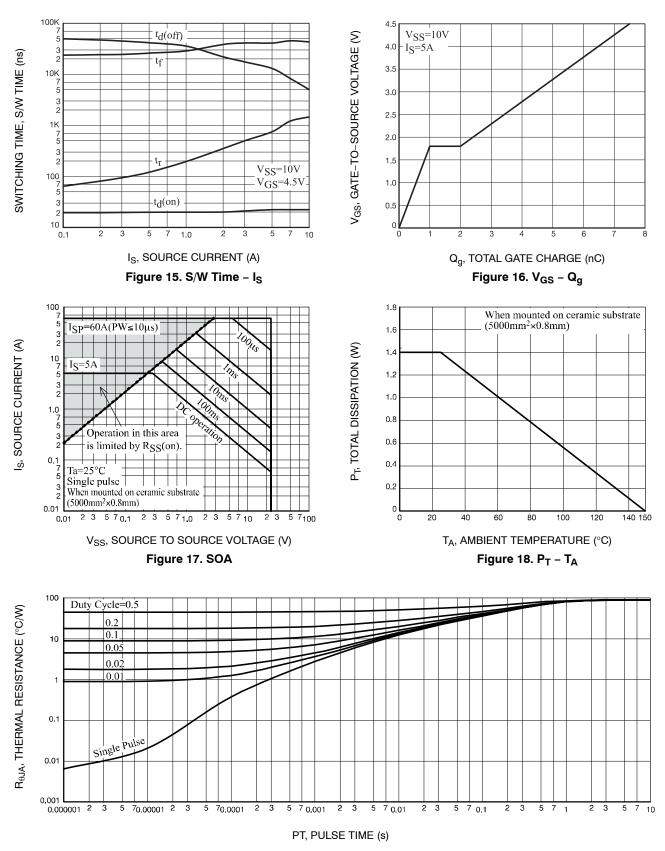


Figure 19. $R_{\theta JA}$ – Pulse Time

PACKAGE DIMENSION

EFC4626R-TR (Unit: mm)

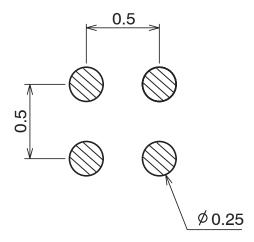


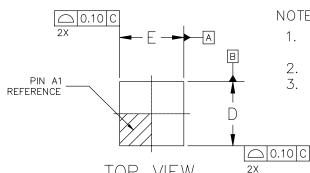
Figure 20. Recommended Soldering Footprint

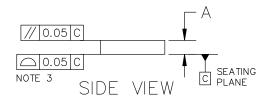




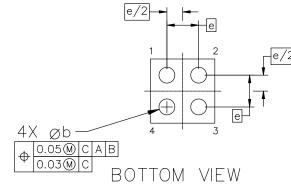
WLCSP4, 1.01x1.01x0.20, 0.50P CASE 568AK **ISSUE C**

DATE 05 NOV 2024





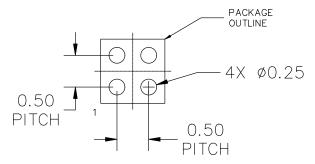
TOP VIEW



NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
- CONTROLLING DIMENSION: MILLIMETERS.
- COPLANARITY APPLIES TO THE SPHERICAL CROWNS OF THE SOLDER BALLS.

MILLIMETERS					
DIM	MIN	MAX			
А	0.18	0.20	0.22		
b	0.22	0.25	0.28		
D	0.99	1.01	1.11		
Е	0.99	1.01	1.11		
е	0.50 BSC				



RECOMMENDED MOUNTING FOOTPRINT

*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques References manual, SOLDERRM/D.

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DESCRIPTION:	WLCSP4, 1.01x1.01x0.20, 0.50P		PAGE 1 OF 1		

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